HD Communications Corp.

HD31202
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Rack mounted system
Class AB linear GaN design
Instantaneous wide bandwidth
Suitable for all single channel modulation standards
Built-in protection circuits
High reliability and ruggedness

ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	1.0 - 2.5 GHz	
Power Output @ Saturation	1000 Watt Min	CW
Power Gain	60 dB Min	
Power Gain Flatness	3.0 dB p-p Max	Constant input power
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	50dBm/Tone, Δ = 1MHz
Harmonics	-20 dBc Typ	At rated output power
Non Harmonics Spurious	-60 dBc Max	
Operating Voltage	180 - 240 VAC	
Power Consumption	4.5 KW Max	At rated Pout
Max Input Power	+8 dBm	< 10 Sec without damage
Load VSWR Protection	∞ : 1	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensing

MECHANICAL SPECIFICATIONS

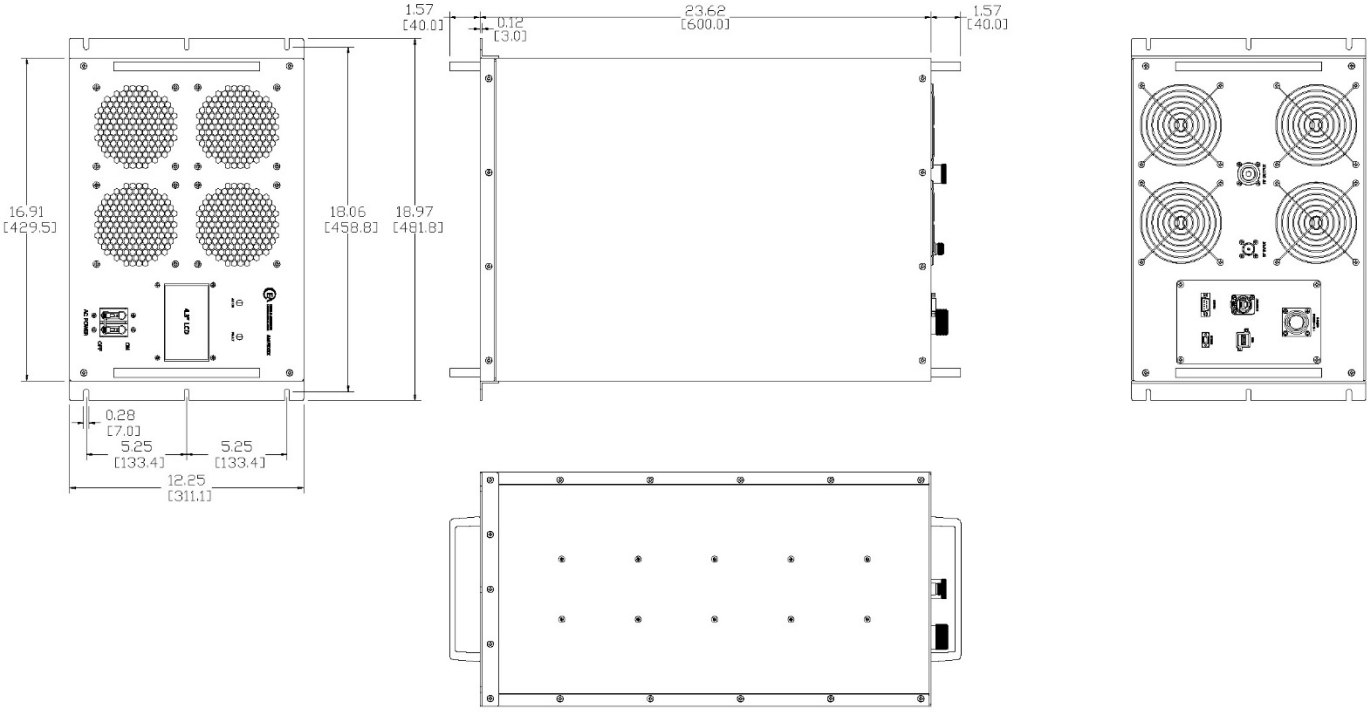
Parameter	Specification	Notes
Dimensions W x H x D	430 x 311 x 600 mm	R7U Rack Mount Chassis
Weight	45 Kg	
RF Connectors In / Out	Type-N Female / 7/16 DIN	Front Panel Standard
AC Power / Interface	IEC 60320-C14 / 9-Pin D-Sub	Or equivalent
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control: FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, Optional GPIB Interface	Remote Bluetooth application

332C Dante Ct. Holbrook, NY 11741 Phone: 631-588-3877 Fax: 631-648-0518
www.rfcomp.com www.rfamplifiers.com sales@hdcom.com

HD Communications Corp.

HD31202
SOLID STATE HIGH POWER AMPLIFIER

OUTLINE DRAWING



332C Dante Ct. Holbrook, NY 11741 Phone: 631-588-3877 Fax: 631-648-0518
www.rfcomp.com www.rfamplifiers.com sales@hdcom.com